

## FEATURE ARTICLE

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View Journal | View IssueNew Si–O–C composite film anode materials for  
LIB by electrodeposition

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Silicon is one of the most promising materials for lithium secondary battery anodes. However, silicon anodes have a critical drawback to their practical application, which is capacity degradation due to pulverization of the active material by the large volume change of silicon during charge–discharge cycles. This paper reviews recent studies on silicon-based anodes that have attempted to overcome this poor cycle durability through structural control such as through thin films, porous structures, core–shell structures, and by alloying with other metals, and by application of proper binders. Among them, binder-free Si–O–C composite films prepared by electrodeposition exhibit outstanding cycle durability. The origin of this excellent durability is discussed in depth from the standpoint of chemical and morphological changes. Consequently, the combination of active materials such as Si and  $\text{Li}_2\text{Si}_2\text{O}_5$  and inactive materials such as  $\text{Li}_2\text{O}$ ,  $\text{Li}_2\text{CO}_3$ , and organic compounds is suggested to result in outstanding properties as a lithium secondary battery anode.

## Introduction

The history of secondary batteries, which reversibly store electrical energy as chemical energy, began with the invention of the lead-acid battery in 1859. Lead-acid batteries are still widely used as a power source for vehicle start-up and as backups for commercial power in industry because of their relatively high voltage, *ca.* 2 V, and moderate price despite their heaviness and

toxicity. Fig. 1 shows the history of the secondary battery and future targets. The invention of the nickel–cadmium (NiCd) battery influenced the development of portable electronic devices because of their high power and tolerance against over-discharging and prolonged storage. The development of the nickel–metal–hydride (NiMH) battery was the trigger to making portable electric devices widespread by replacing NiCd batteries because of its high energy density. Commercial production of hybrid electric vehicles (HEV) started in 1997 using the NiMH battery as a power source. Finally, the commercialization of the lithium-ion battery (LIB) has enabled the realization of lap-top computers and high performance smart phones.

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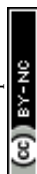
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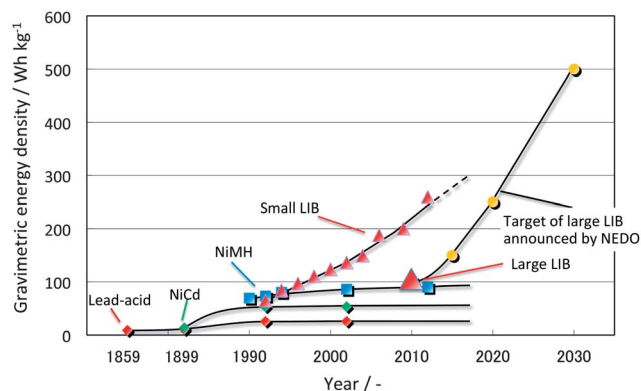


Fig. 1 History of secondary batteries and targets for the near future.

Furthermore, progress in LIBs has encouraged the development of electric devices with higher power consumption. The circumstances surrounding energy storage have been changing in recent years. Namely, new applications of LIBs in electric vehicles and stationary grid energy storage have arisen.<sup>1</sup> For example, battery electric vehicles (BEV), which use LIBs as their power source, became commercially available in 2010. The development of LIBs is therefore subject to strong demands including increased safety, longer life, lower cost, higher energy density, and higher power. High energy density is especially required for electric vehicles to enable long distance driving. Therefore, enhancement of anode and cathode material capacity is essential for the widespread adoption of electric vehicles. Capacity enhancement must be achieved for both anode and cathode materials; because space is usually limited in a battery, the enhancement of the capacity of one electrode is not enough to enhance the capacity of the overall cell. Fig. 2 shows an estimation of energy density with cathode capacity in a 18650 cylinder-type cell. If the capacity of the anode is fixed to 372 mA h g<sup>-1</sup>, the over capacity increase is limited even if the capacity of the cathode is increased drastically. A battery that delivers an

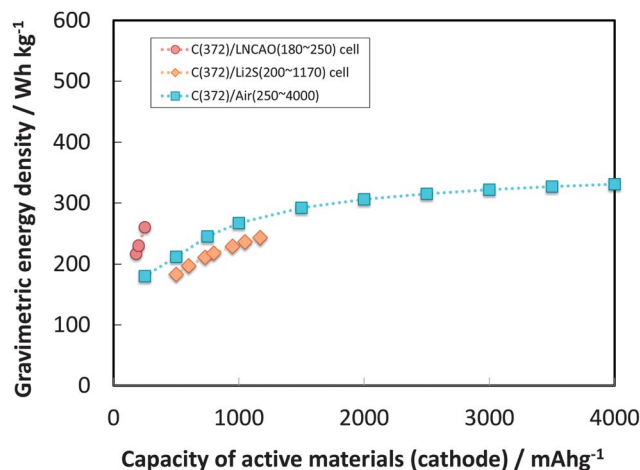


Fig. 2 Estimation of energy density increase with capacity for various cathodes (LiNi<sub>x</sub>Co<sub>y</sub>Al<sub>z</sub>O<sub>2</sub>, Li<sub>2</sub>S, O<sub>2</sub>). Gravimetric energy density values were calculated on the basis of a 18650 cylinder-type cell with graphite anode. Values in brackets in the graph legend are the capacities of the active materials used in the calculations.

energy density of 300 W h kg<sup>-1</sup> would be difficult to achieve with a graphite anode, and would also be difficult as long as a conventional cathode is used. An increase in the capacities of both anode and cathode would enable the energy density to be increased to over 300 W h kg<sup>-1</sup>. For example, a battery composed of an anode material with a capacity of 1000 mA h g<sup>-1</sup> and a cathode material having with capacity of 800 mA h g<sup>-1</sup> would deliver an energy density of *ca.* 300 W h kg<sup>-1</sup>.

Under these circumstances, silicon is one of the most promising anode materials because its theoretical capacity (4200 mA h g<sup>-1</sup>) is much higher than that of graphite (372 mA h g<sup>-1</sup>). In addition, because the Clarke number of silicon is 25.8, the cost of the active anode material can be reduced. These advantages are beneficial for both industry and consumers. However, silicon has a critical problem: silicon anodes cannot



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maintain their structure during charge–discharge cycles because of the large change in the volume of the active material that occurs during the cycles, which results in capacity degradation.<sup>2</sup> Recently, Lee *et al.* provided a deep insight into lithiation of crystalline silicon.<sup>3</sup> They used Si nanopillars with circular cross-section in shape with three different axial orientations ( $\langle 100 \rangle$ ,  $\langle 110 \rangle$ , and  $\langle 111 \rangle$ ) as a model system to show cross-sectional dimensional changes during lithiation. Upon lithiation, the cross-sections of nanopillars with  $\langle 100 \rangle$ ,  $\langle 110 \rangle$ , and  $\langle 111 \rangle$  axial orientations expand into cross, ellipse, and hexagonal shapes, respectively. The authors explained this phenomenon by identifying a high-speed lithium ion diffusion channel along the  $\langle 110 \rangle$  direction, which causes preferential volume expansion along this direction. Upon further lithiation the amorphous phase begins to form at the surface of the  $\langle 110 \rangle$  ion channels where the Li concentration is highest. Interestingly, the  $\langle 111 \rangle$  and  $\langle 100 \rangle$  nanopillars shrink in height after partial lithiation, while  $\langle 110 \rangle$  nanopillars increase in height. The length contraction is considered to be due to the collapse of the  $\{111\}$  planes early in the lithiation process.

## Approaches on silicon based anode

To solve this volume change problem, several approaches based on the control of silicon-based anode structure or composition have been carried out. Selected examples are introduced below.

### Thin silicon films

Graetz *et al.* reported a thin Si film (100 nm) lithium secondary battery anode prepared using physical vapor deposition (PVD) by vacuum evaporation directly onto the planar current collector.<sup>4</sup> The evaporated Si film was amorphous in structure, which avoided the formation of stoichiometric compounds that would have otherwise resulted in considerable suppression of local stress gradients because of electrochemical alloying. The thin Si film anode exhibited an initial discharge (delithiation) capacity of 2500 mA h (g of Si)<sup>−1</sup> at 0.25 C rate with a coulombic efficiency of 71% on the first cycle, and a stable discharge capacity of 1800 mA h g<sup>−1</sup> over 50 cycles. After 20 cycles, the thin film exhibited a mean capacity loss of 8 mA h g<sup>−1</sup> per cycle. Ohara *et al.* reported a thinner Si film anode (50 nm) prepared by PVD using vacuum evaporation from a negative doped Si source.<sup>5</sup> The thin Si anode exhibited enhanced specific capacity compared to that achieved with an intrinsic Si source, and a stable discharge capacity of 3800 mA h (g of Si)<sup>−1</sup> at 1 C rate over 200 charge–discharge cycles. The thin Si anode prepared by PVD also had an amorphous like structure even after charge–discharge cycles. Thus, an amorphous like structure including a polycrystalline structure can improve the cycle durability of silicon-based anode because amorphous silicon itself can act as a buffer layer during charge–discharge cycles.

Such thin film anodes have the advantage of direct deposition on the current collector without any binder or electrically conductive additives. However, thin film anodes have an essential drawback in the fact that it is difficult to improve their energy density by increasing their thickness, because thicker

films suffer from more stress because of volume change during charge–discharge cycling. Although studies have been carried out to increase the anode film thickness by roughening the surface of the current collector, the maximum thickness has so far been limited to 3.6 μm.<sup>6</sup>

### Porous silicon powders

Kim *et al.* reported a three-dimensional and porous Si particle anode<sup>7</sup> prepared by thermal annealing of SiO<sub>2</sub> and butyl capped Si particles and etching of SiO<sub>2</sub>. The resulting porous Si particles had bulk sizes of greater than 20 μm with interconnected pores of 200 nm in size and *ca.* 40 nm wall thickness. The porous structure could accommodate stress during charge–discharge cycling without experiencing pulverization for 100 charge–discharge cycles, and maintained a charge capacity of greater than 2800 mA h (g of Si)<sup>−1</sup> at 0.2 C rate. Ge *et al.* reported porous doped Si nanowire anodes with a pore diameter and wall thickness of *ca.* 8 nm prepared by direct etching of boron-doped silicon wafers.<sup>8</sup> The resulting porous Si nanowire anode exhibited a first discharge capacity of 3038 mA h g<sup>−1</sup>, and after 250 cycles its discharge capacity remained above 1960 mA h g<sup>−1</sup> at 0.5 C rate, indicating good structural stability. Moreover, the porous Si nanowire anode delivered a discharge capacity of above 1000 mA h g<sup>−1</sup> even after 2000 cycles.

Porous materials are one of the most promising approaches for realization of Si based anodes because a porous structure can shorten the diffusion length in the solid phase and accommodate stress during charge–discharge cycling without pulverization. These phenomena have also been reported for Sn-based anode systems.<sup>9</sup> In addition, particle and nanowire powders are favorable for industry because they are suitable for the conventional processes used to prepare graphite anodes, even though the process requires a binder and electron conductive additives. However, such high surface area powder materials often suffer from large irreversible capacity in the initial several charge–discharge cycles because solid electrolyte interphase (SEI) formation, which consumes lithium, occurs in proportion to the surface area.<sup>10</sup> This is a serious problem when assembling full cells, in which limited space is available for the anode and cathode materials.

### Silicon powders with unique structures

Zhang *et al.* reported core–shell Si/SiO nanocomposites.<sup>11</sup> The core–shell Si/SiO, which was by a sol–gel method and a following heat-treatment process, was *ca.* 50 nm of the core in average size and in face-centered cubic structure. The core–shell Si/SiO nanocomposite exhibited a discharge capacity of 538 mA h (g of Si)<sup>−1</sup> after 20 cycles, which is 65% of the discharge capacity at the 1st cycle. Meanwhile, the anode of the Si nanoparticles showed a rapid capacity fading and retains only 10.3% of the original capacity after 20 cycles. The capacity loss of crystalline silicon nanoparticles could be ascribed to the aggregation of nano-sized active particles caused by electrochemical alloying reaction with lithium and the destruction of crystalline structure accompanied by severe volume expansion.<sup>12</sup> On the other, the electroactive Si particles coated by SiO





could not combine together because of the existence of the SiO shell. Simultaneously, SiO can also absorb and retain a large quantity of lithium ions. Because the Si–O bond is generally twice as strong as the Si–Si bond, the SiO anode exhibits a good cycling performance. During the lithiation process, SiO can change to form lithium silicates, which expand only half as much as Li–Si alloys, and the Li-silicates serve as a buffer to alleviate volume expansion of the Si nanoparticles, mitigating the destruction of the Si crystalline structure.<sup>13</sup> Wu *et al.* demonstrated double-walled silicon nanotubes (DWSiNTs) consisting of Si nanotubes surrounded by ion-permeable silicon oxide shells.<sup>14</sup> The DWSiNT was prepared by using a templating method combined with the electrospinning method. The double-walled structure enables the prevention of the outer surface of the silicon nanotube from expansion by the oxide shell, and the expanding inner surface is not exposed to the electrolyte, resulting in a stable SEI. As a result, the DWSiNT anode exhibited discharge capacities of *ca.* 2971 mA h (g of Si)<sup>−1</sup> and 1780 mA h (g of DWSiNT)<sup>−1</sup> at C/5 rate, *ca.* 940 mA h (g of Si)<sup>−1</sup> and 600 mA h (g of DWSiNT)<sup>−1</sup> at 12 C rate with 80% capacity retention at room temperature even after 6000 charge–discharge cycles. Furthermore, the DWSiNT anode can operate even at 20 C rate, delivering the discharge capacity of *ca.* 850 mA h (g of Si)<sup>−1</sup>. Hwang *et al.* reported core–shell fibers consisting of Si nanoparticle cores wrapped in carbon shells (SiNPs@C).<sup>15</sup> The core–shell fibers, which were prepared by the electrospinning technique, had a one-dimensional fibrous morphology of *ca.* 1 μm diameter that encapsulated Si particles of *ca.* 50 nm diameter with compact packing. The core–shell fiber anode exhibited a discharge capacity of 1384 mA h g of (SiNPs@C)<sup>−1</sup> at C/10 rate, with almost no capacity loss after 300 charge–discharge cycles. Zhou *et al.* reported a kind of core–shell structured Si anode in which Si nanoparticles (<200 nm) on graphene sheet were coated by an amorphous carbon shell of 2–3 nm in thickness.<sup>16</sup> This core–shell particle anode exhibited an initial discharge capacity of 1328 mA h (g of Si, graphene, and amorphous carbon)<sup>−1</sup> at C/3 rate and a discharge capacity of 902 mA h g<sup>−1</sup> after 100 charge–discharge cycles. Such modifications by carbonous materials are effective in enhancing electric conductivity,<sup>17</sup> reducing electrolyte decomposition,<sup>18–21</sup> and buffering volume changes during charge–discharge cycling.<sup>22</sup> Okubo *et al.* reported a Si thin flake anode (4–5 μm in size and 100 nm in thickness) prepared by PVD using vacuum evaporation.<sup>23</sup> The Si thin flake anode exhibited an initial discharge capacity of 2651 mA h (g of silicon)<sup>−1</sup> at C/6 rate and *ca.* 2250 mA h g<sup>−1</sup> after 50 charge–discharge cycles when vinylene carbonate (VC) was used as an electrolyte additive. A thin flake shape has the advantages of shortening the lithium diffusion length without increasing the surface area, and increasing the tap density compared with nanoparticles. Saito *et al.* reported the dependence of the thickness for the Si thin flake anodes.<sup>24</sup> According to their paper, a Si thin flake of 200 nm in thickness can work as well as a flake of 100 nm in thickness.

These silicon powders with unique structures are also favorable for industry, as mentioned above. In addition, carbon-coating treatment can reduce the irreversible capacity

attributed to electrolyte decomposition.<sup>19–21</sup> Consequently, these materials would be some of the most promising ones for practical realization.

### Silicon alloyed with other metals

Anani *et al.* reported intermetallic compounds such as silicides (M–Si) as anode materials for lithium batteries.<sup>25</sup> Among these materials, Choi *et al.* reported a Fe–Si anode<sup>26</sup> and Zhou *et al.* reported a Ni–Si anode.<sup>27</sup> The Fe–Si anode was prepared by radio frequency (RF) magnetron sputtering of a Fe–Si alloy target and was evaluated in an ionic liquid (IL) electrolyte system. The anode exhibited an initial discharge capacity of 1073 mA h (g of FeSi<sub>2.7</sub>)<sup>−1</sup> and 756 mA h g<sup>−1</sup> at 0.3 C rate in conventional liquid electrolyte and IL electrolyte, respectively. The discharge capacity declined to 783 mA h g<sup>−1</sup> and 694 mA h g<sup>−1</sup> after 100 charge–discharge cycles in the conventional and IL electrolytes, respectively. A.C. impedance analysis revealed that the difference was due to the stability of the interface between the electrolyte and the electrode. The Ni–Si anode was prepared by pulse laser deposition from a target made from Ni and Si powders. The anode exhibited an initial discharge capacity of *ca.* 1120 mA h (g of NiSi<sub>1.2</sub>)<sup>−1</sup> at *ca.* 0.013 C rate, estimated from the theoretical capacity of Si. The discharge capacity after 100 charge–discharge cycles was *ca.* 1000 mA h g<sup>−1</sup>.

The alloying of silicon with other metals is effective in increasing the electric conductivity of the material and suppressing the pulverization of the active material. This effect has also been confirmed in Sn-based anode systems.<sup>28,29</sup>

### Approaches on polymer binder

Much research has been devoted to the design of active materials to moderate the stress due to the volume change of the active materials. Meanwhile, the other approaches to inhibit the mechanical fracture of silicon-based anode, namely an improvement of electrically inactive materials such as binders, have been also reported. Carboxymethyl cellulose (CMC) and polyacrylic acid (PAA) binders are well known to perform better than polyvinylidene fluoride (PVdF) for silicon-based anodes.<sup>30,31</sup> Unlike PVdF is attached to Si particles *via* weak van der Waals forces only, CMC and PAA are bonded to the surface of silicon particles *via* a covalent ester bonding between the free carboxylic acid groups of CMC and PAA and the OH groups on silicon particles.<sup>31,32</sup> The stronger interactions enable the prevention of destruction of the electric network under the large volume change during charge–discharge cycles. Furthermore, these binders, which bond with silicon particles by hydrogen bonding between the carboxyl groups of the binder and the silicon oxides on the silicon particles, were proposed to exhibit a self-healing effect and reform if locally broken.<sup>33</sup> Kovalenko *et al.* reported alginate, which is a high-modulus natural polysaccharide extracted from blown algae, as a binder to stabilize an operation of the silicon powder anode.<sup>34</sup> The silicon powder anode with the alginate binder exhibited a reversible capacity of *ca.* 1700 mA h (g of Si)<sup>−1</sup> after 100 cycles at 1 C rate at room temperature. Alginate macromolecules, which are more polar than the CMC polymer,



are attributed to the better cycle durability. Koo *et al.* reported a cross-linked polymeric binder, namely a three-dimensional interconnected network of PAA and Na-CMC. The nanosized silicon powder formed by the binder exhibited a high reversible capacity of over 2000 mA h (g of Si)<sup>-1</sup> after 100 cycles at 0.1 C rate at 30 °C and maintains a superior capacity of 1500 mA h g<sup>-1</sup> at 10 C rate at 60 °C.<sup>32</sup>

### Electrodeposited Si-O-C composite film

As mentioned above, there have been many studies on the Si-based anode and binder. Among them, we have successfully developed a binder-free Si-O-C composite film for lithium secondary battery anodes by means of electrodeposition.<sup>35–38</sup> The Si-O-C composite film was electrodeposited from a bath containing silicon tetrachloride as a silicon source, tetrabutylammonium perchlorate as a supporting electrolyte, and propylene carbonate solvent directly onto a copper substrate. The electrodeposition of silicon is considered to occur with accompanying decomposition of the organic solvent, leading to the formation of a Si-O-C composite film.

### Charge-discharge property of the Li-Si-O-C composite anode

The electrochemical performance of a Li-Si-O-C composite anode, which was firstly electrochemically lithiated, was examined through a constant current (CC) – constant voltage (CV) charge (lithiation) – CC discharge (delithiation) test. Fig. 3 shows the charge and discharge capacity values of the Li-Si-O-C composite anode under a loading current of 250  $\mu\text{A cm}^{-2}$ , which corresponds to a value of 1.0 in C-rate. At the initial stage, the Li-Si-O-C composite anode exhibited a high discharge capacity of above 1200 mA h (g of Si)<sup>-1</sup>. Then, the discharge capacity decreased to 900 mA h (g of Si)<sup>-1</sup> until the 20th cycle. After the 20th cycle, the discharge capacity increased beyond 1100 mA h (g of Si)<sup>-1</sup> and then gradually decreased, maintaining a value higher than 1000 mA h (g of Si)<sup>-1</sup> for more than 2000 cycles. The coulombic efficiency during charge-discharge cycling was found to be higher than 98%, except for a few initial cycles. The low efficiency in the first cycle was attributed to the consumption of reducing charges by Si oxide<sup>39,40</sup> and SEI formation<sup>21,41</sup> as discussed with EELS and XPS data below.

The potential profiles measured during charge-discharge cycling (bottom, Fig. 3) give us a deeper insight. A negative potential overshoot was observed during the initial lithiation process on the Si-O-C composite film because of the nucleation of a new phase, namely the Li<sub>2</sub>O phase.<sup>40</sup> The capacity for the first charge (lithiation) was 4731 mA h (g of Si)<sup>-1</sup>, while the capacity for the first discharge (delithiation) was 1403 mA h (g of Si)<sup>-1</sup>. This large irreversible capacity is attributed mainly to the conversion of SiO<sub>x</sub> to SiLi<sub>y</sub> and Li<sub>2</sub>O,<sup>39,40</sup> and partly to SEI formation,<sup>21,41</sup> indicated by the potential plateau above 0.4 V vs. Li/Li<sup>+</sup> in Fig. 3 (bottom) and confirmed by cyclic voltammograms (see ESI of ref. 36). The potential plateau for delithiation below 0.6 V vs. Li/Li<sup>+</sup> during the first discharge was confirmed, and corresponded to the anodic peaks repeated at 0.32 and 0.46 V vs. Li/Li<sup>+</sup> in the cyclic voltammogram (see ESI of ref. 36), the results of which accord with the delithiation of silicon.<sup>42</sup> After

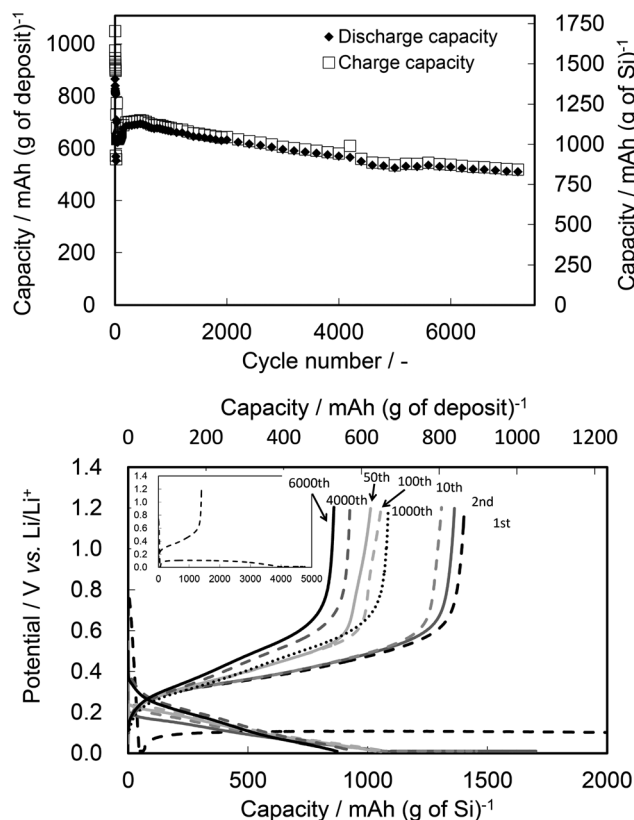
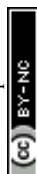


Fig. 3 Plots of charge-discharge capacity of the Si-O-C composite anode against the number of cycles (upper) and potential profiles during charge-discharge cycling at various cycle numbers (bottom). The inset in the bottom shows potential profiles during the first lithiation and delithiation. The capacity values were normalized with respect to the weight of the initial deposit or the calculated amount of Si in the deposit. The applied current density was 250  $\mu\text{A cm}^{-2}$  (1.0 C-rate). Reproduced from data published in ref. 36.

the first cycle, the Li-Si-O-C composite anode was charged at a potential below 0.3 V vs. Li/Li<sup>+</sup>, and discharged at a potential plateau below 0.6 V vs. Li/Li<sup>+</sup>. For 300 cycles, the electrode potential dropped to about 0.2 V vs. Li/Li<sup>+</sup> at the initial stage of charging in each cycle and then decreased while the current was being passed. The initial potential shifted towards 0.4 V vs. Li/Li<sup>+</sup> with increasing cycle number. The potential profile observed during charging did not change significantly after the 300th cycle. The potential profiles during discharge were identical at all stages except for the amount of discharge capacity, which was found to be above 1000 mA h (g of Si)<sup>-1</sup> or above 630 mA h (g of deposit)<sup>-1</sup> even after 2000 cycles. Moreover, the Li-Si-O-C composite anode delivered a discharge capacity of 831 mA h (g of Si)<sup>-1</sup> or 512 mA h (g of deposit)<sup>-1</sup> even after 7000 cycles.

### Analysis of the Si-O-C composite film and Li-Si-O-C composite anode with charge-discharge cycle

To reveal the reason why the Li-Si-O-C composite film exhibited outstanding durability for more than 7000 cycles, the Si-O-C composite film and Li-Si-O-C composite anode were



analysed from the standpoints of changes in morphology and chemical composition.

### Change of the Si–O–C composite film and Li–Si–O–C composite anode morphology with charge–discharge cycle

FESEM images of the Si–O–C composite film prepared by the electrodeposition of silicon are shown in Fig. 4. The images of the as electrodeposited Si–O–C composite film show a macroscopically homogeneous deposit. The enlarged FESEM image indicates that the deposit consisted of sub-micrometer clusters with voids that covered the Cu substrate. Plane view FESEM images of the Li–Si–O–C composite anode after the first lithiation are shown in Fig. 4. After the first lithiation, the voids that were observed in the as electrodeposited Si–O–C composite film before the first lithiation decreased in size. This is attributed to the expansion of silicon and the formation of  $\text{Li}_2\text{O}$  by the lithiation of  $\text{SiO}_x$  leading to a reduction of the space in the voids and also to SEI formation,<sup>21,41</sup> leading to the covering of the film. Although the SEI was formed on the Li–Si–O–C composite anode, the particles which were observed on the Si–O–C composite film were only slightly visible on the Li–Si–O–C composite anode. FESEM images of the Li–Si–O–C composite anodes after the 10th and 300th cycles are also shown in Fig. 4. The particles observed on the Li–Si–O–C composite anode surface after the first lithiation were absent after the 10th cycle. This phenomenon must be due to the progress of SEI formation, which is evidenced by the lower columbic efficiency observed during the initial cycles (Fig. 3). Cracking of the Li–Si–O–C composite anode caused by a large volume change of silicon, which is a problem associated with the Si anode system,<sup>18,20,43</sup> was not observed. This was attributed to a uniform

reaction of the well-dispersed  $\text{SiO}_x$  at the nanometer scale as confirmed by STEM-EDX (Fig. 6), and to the buffering effect of surrounding decomposition products of the organic solvent. Although cracking was observed to a slight extent after the 100th cycle, the surface morphology was almost unchanged even after the 300th cycle. The results of the FESEM observation imply that the suppression of crack formation was the reason for the excellent cycle durability exhibited by the Li–Si–O–C composite anode. Fig. 5 shows the variation in thickness of the

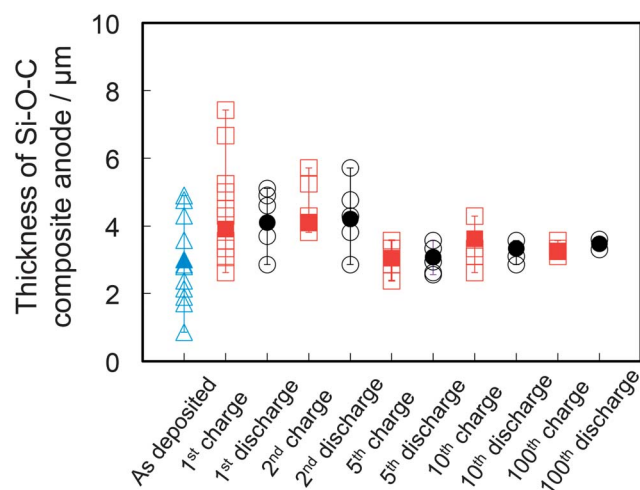


Fig. 5 Film thickness of the as electrodeposited Si–O–C composite film and of the Li–Si–O–C composite anode after the 1st charge, 1st discharge, 2nd charge, 2nd discharge, 5th charge, 5th discharge, 10th charge, 10th discharge, 100th charge, and 100th discharge. The film thickness was measured at fractured cross-sections for a number of samples. Reproduced from the data published in ref. 37.

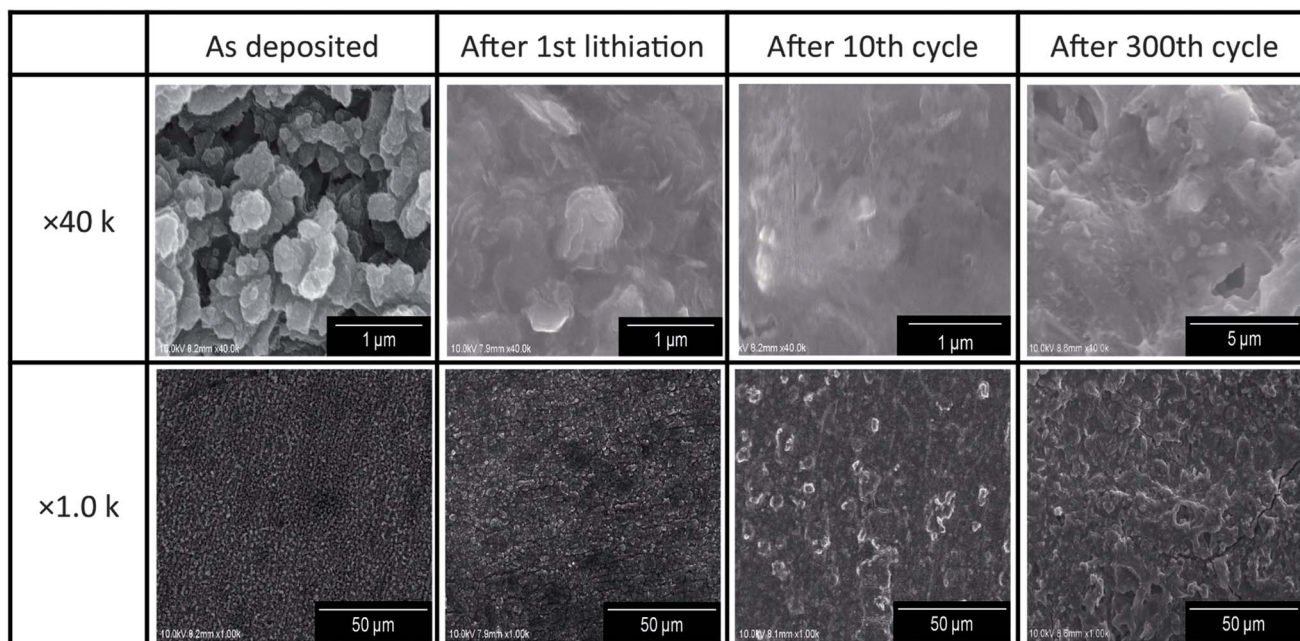


Fig. 4 Plane view FESEM images of as the electrodeposited Si–O–C composite film and Li–Si–O–C composite anodes after the 1st charge, the 10th cycle, and after the 300th cycle. Reproduced from data published in ref. 36.

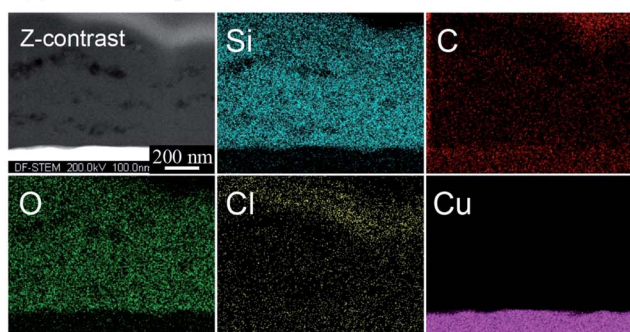




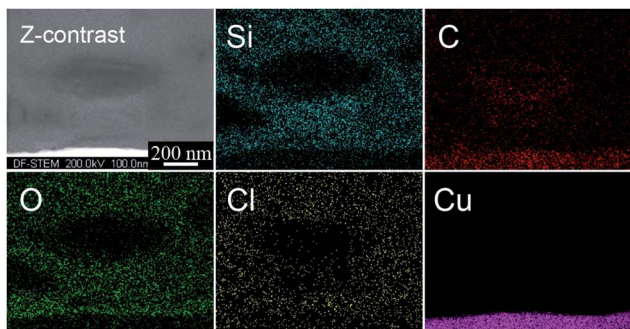
as deposited Si–O–C composite film and of the Li–Si–O–C composite anodes after the 1st charge, 1st discharge, 2nd charge, 2nd discharge, 5th charge, 5th discharge, 10th charge, 10th discharge, 100th charge, and 100th discharge, as measured from SEM images of fracture cross-sections of a number of samples after electrodeposition. The thickness of the as electrodeposited Si–O–C composite film varied from *ca.* 1 to 5  $\mu\text{m}$  because of the roughness of the deposit, as seen in Fig. 4. After the 1st charge, the overall film thickness of the Li–Si–O–C composite anode showed a tendency to increase, caused by the alloying of silicon with lithium. Increased film thickness would also be due to SEI formation.<sup>41,44</sup> After the 1st discharge, the distribution of the film thickness became more uniform. Especially, the thicker parts of the Li–Si–O–C composite anode showed a tendency to become thinner after the 1st charge,

which should be due to the dealloying of silicon from lithium. This non-uniform variation may be due to SEI formation during the 1st charge and the initial structure of the Si–O–C composite film. The projecting parts of the film delithiated preferentially during the 1st discharge. The film thickness distribution tended to become uniform up to the 100th cycle; in fact, the projecting part of the deposit reorganized into the void space during charge–discharge cycles. Furthermore, the variation of the film thickness between charged and discharged states showed a tendency to become smaller. Thus, after several charge–discharge cycles the Li–Si–O–C composite anode, which buffers against volume change during charge–discharge cycles, is likely to be formed with not only SEIs such as  $\text{Li}_2\text{O}$ ,  $\text{Li}_2\text{CO}_3$ , and organic compounds, but also inorganic phases such as lithium silicates as discussed below. The smaller variation of the film thickness between charged and discharged states suggests that the Li–Si–O–C composite anode varied correspondingly between dense and non-dense states, respectively.

(a) Si–O–C composite film



(b) Li–Si–O–C composite anode after 1st charge



(c) Li–Si–O–C composite anode after 100th discharge

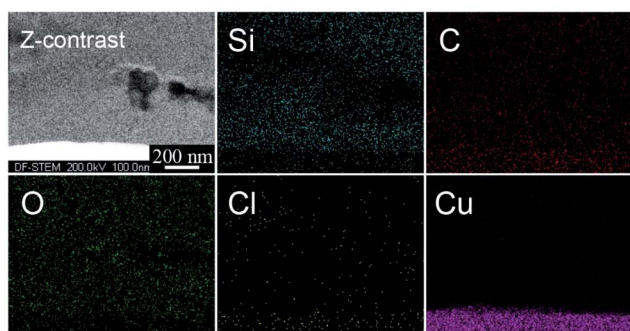


Fig. 6 Cross-sectional Z-contrast images and micro EDX mapping of Si, C, O, Cl, and Cu elements of the Si–O–C composite film (a), Li–Si–O–C composite anode after the 1st charge, (b), and after the 100th discharge (c). The contrast in the Z-contrast image depends on the average atomic number. Reproduced from data published in ref. 37.

#### Change in composition of the Si–O–C composite film and Li–Si–O–C composite anode with charge–discharge cycle

Fig. 6 shows STEM-EDX mapping of Si, C, O, Cl, and Cu elements in the Si–O–C composite film and the Li–Si–O–C composite anodes after the 1st charge and the 100th discharge. The EDX mapping shown in Fig. 6(a) reveals uniform dispersion of Si, O, and C at the nano-scale level and incorporation of Cl derived from  $\text{SiCl}_4$ , which was the source of silicon for the electrodeposition. Fig. 6(b) also indicates homogeneous dispersion of Si, O, and C at the nano-scale, and Fig. 6(c) indicates that these elements were still homogeneously dispersed after the 100th discharge.

Fig. 7 shows cross-sectional Z-contrast (ZC) images, which were obtained by high-angle annular dark-field STEM (HAADF-STEM), and bright field (BF) images, which were obtained by annular bright-field STEM (ABF-STEM), of the Si–O–C composite film and the Li–Si–O–C composite anodes after the 1st charge and the 100th discharge. Fig. 7(a) and (d) indicate that the Si–O–C composite film was uniformly deposited and had pores of 10–100 nm in size. The cross-sectional images are considered to have been observed at the thinnest part because the surface of the Si–O–C composite film was rough as confirmed by the thickness variation shown in Fig. 5 and by the SEM images shown in Fig. 4. The crystallinity of the Si–O–C composite anode was confirmed to be completely amorphous from the transmission electron diffraction (TED) pattern obtained from the STEM (see the ref. 37). Pores measuring *ca.* 500 nm in size, which is larger than the pores observed in the Si–O–C composite film, were observed on the Li–Si–O–C composite anode after the 1st charge (Fig. 7(b) and (e)). These pores would have been formed during the charge process, in which inhomogeneous expansion of silicon and  $\text{Li}_2\text{O}$  formation take place because of the reaction with lithium. The contrasts in the HAADF-STEM and BF images changed from homogeneous to the inhomogeneous contrasts observed for the Si–O–C composite film, which means that the Li–Si–O–C composite anode was composed of multiple phases after the 1st charge.



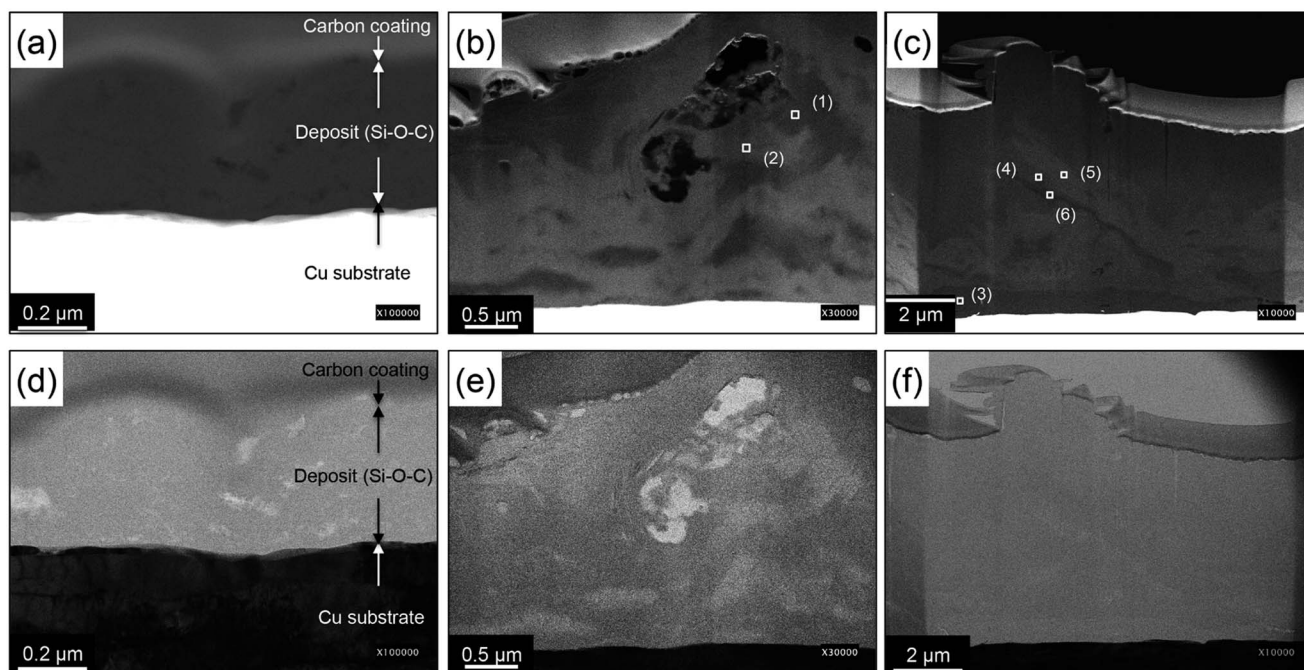


Fig. 7 Cross-sectional Z-contrast images and BF images of the Si-O-C composite film (a) and (d), and the Li-Si-O-C composite anodes after the 1st charge (b) and (e), and 100th discharge (c) and (f), respectively. Samples were prepared by focused ion beam. The contrast in the Z-contrast image depends on the average atomic number. Reproduced from data published in ref. 37.

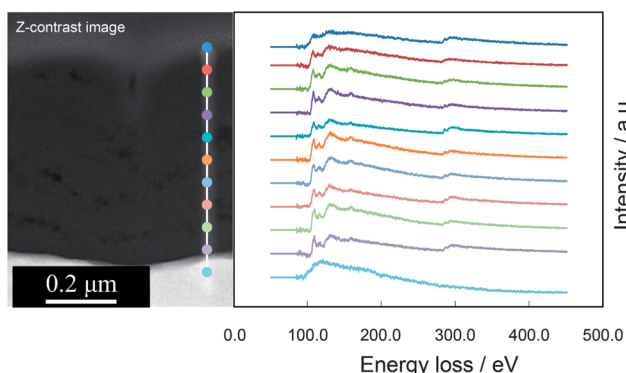


Fig. 8 Cross-sectional Z-contrast image of the Si-O-C composite film and EELS spectra of Si on the Si-O-C composite film obtained at the colored points, the colors of which correspond to those of the EELS spectra. The baselines in each graph are displaced for clarity.

The pores that were observed in the Si-O-C composite film and the Li-Si-O-C composite anode after the 1st charge clearly decreased in number after the 100th discharge (Fig. 7(c) and (f)). This implies that decomposition of the electrolyte, such as by SEI formation, takes place even in the Li-Si-O-C composite anode as the number of charge-discharge cycles increases, and that the repeated expansion and contraction of silicon accelerates the uniform dispersion of Li, Si, O, and C elements. The inhomogeneous contrasts in the HAADF-STEM and BF images also mean that the microstructure of the Li-Si-O-C composite anode had at least two phases after the 100th discharge, as in the microstructure observed after the 1st charge.

The chemical states of Li, Si, C, and O on the Si-O-C composite film and the Li-Si-O-C composite anode after the 1st charge and after 100th discharge were evaluated by EELS. Fig. 8 shows the EELS spectra of Si, C, and O on the Si-O-C composite film obtained at different depths. All peak positions were identified in all spectra, revealing that the Si-O-C composite film was chemically uniform in the depth direction. Fig. 9 shows the EELS spectra of Si, C, and O on the Si-O-C composite film obtained at different points and the Si spectra of standard  $\text{SiO}_2$  and Si samples. Each peak position in the EELS spectra of Si, C, and O was similar even at different points on the sample, which

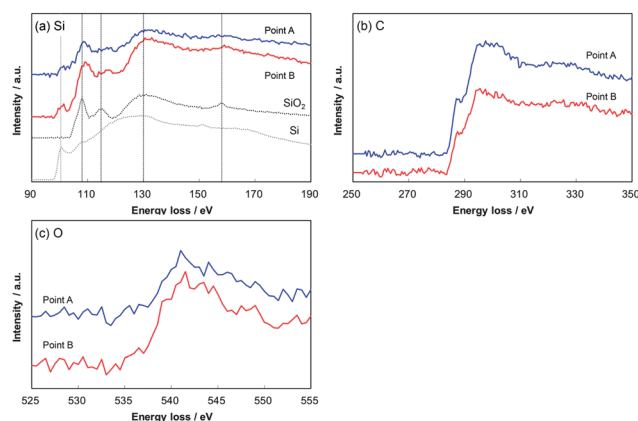


Fig. 9 EELS spectra of Si (a), C (b), and O (c) on the Si-O-C composite film obtained at different locations. The spectra of  $\text{SiO}_2$  and Si standard samples are included for comparison. The baselines in each graph are displaced for clarity. Reproduced from data published in ref. 37.





suggests that the composition of the Si–O–C composite film was chemically uniform as well as has good elemental dispersion. The state of silicon in the Si–O–C composite film was investigated through comparison with standard  $\text{SiO}_2$  and Si samples. The EELS spectra of Si in the Si–O–C composite exhibited a peak attributed to Si and peaks attributed to  $\text{SiO}_2$ . Therefore, the silicon in the Si–O–C composite film was suggested to exist as  $\text{SiO}_x$  ( $0 < x < 2$ ).

Fig. 10 shows the EELS spectra of Li, Si, O, and C in the Li–Si–O–C composite anode after the 1st charge at points 1 and 2 as indicated in Fig. 7(b). The points were selected on the basis of the contrast difference observed in the HAADF-STEM image (Fig. 7(b)). Although the EELS spectra were obtained at several points in the Li–Si–O–C composite anode after the 1st charge, the spectra were classified as either point 1 or point 2, corresponding to the dark area or bright area, respectively, in the HAADF-STEM image. Although the intensities of the Li, Si, O, and C spectra were different, the peak positions were similar to each other. These results suggested that the Li–Si–O–C composite anode had at least two phases after the 1st charge; a Li rich phase and a Si–O rich phase, as confirmed from Fig. 10(a). The spectra of  $\text{Li}_2\text{CO}_3$  and  $\text{Li}_2\text{O}$  standard samples, which are well known to be SEI components,<sup>41</sup> are shown in Fig. 10(a). The comparison suggests the possibility of formation of  $\text{Li}_2\text{O}$  and  $\text{Li}_2\text{CO}_3$  in the Li–Si–O–C composite anode after the 1st charge.

Fig. 11 shows the EELS spectra of Li, Si, O, and C in the Li–Si–O–C composite anode after the 100th discharge at points 3–6 indicated in Fig. 7(c). Although the intensities observed in the Li spectra were different, the existence of Li was confirmed at all points even in the discharged state. These results suggest the existence of irreversible lithium in the form of  $\text{Li}_2\text{O}$ ,  $\text{Li}_2\text{CO}_3$ , and lithium silicates as suggested from the XPS analysis below. The Si spectra measured at points 3 and 5 indicate the possibility of the existence of  $\text{SiO}_2$ . While the states of Li, Si, O, and C were difficult to identify from the EELS spectra, the EELS spectra in Fig. 11 indicate that the Li–Si–O–C composite anode had several

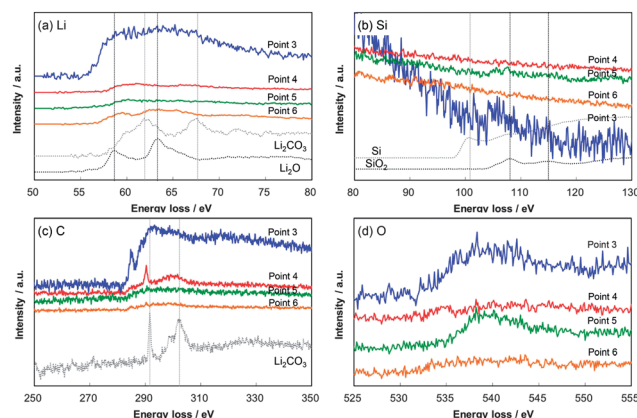


Fig. 11 EELS spectra of Li (a), Si (b), C (c), and O (d) obtained at different locations on the Li–Si–O–C composite anode after the 100th discharge. The spectra of  $\text{SiO}_2$ , Si,  $\text{Li}_2\text{O}$ , and  $\text{Li}_2\text{CO}_3$  standard samples are included for comparison. The baselines of each graph are displaced for clarity. Reproduced from data published in ref. 37.

phases including Li rich and Si–O rich phases after the 100th discharge. In addition, organic phases resulting from the electrolyte decomposition, which cannot be identified by EELS, should exist. Thus, the composite, which contained several phases which do not react with lithium ions such as  $\text{Li}_2\text{O}$ ,  $\text{Li}_2\text{CO}_3$ , and flexible organic phases, would have buffered the volume change caused by the lithiation and delithiation of silicon.

Fig. 12(a)–(d) shows the XPS spectra of  $\text{C}_{1s}$ ,  $\text{Li}_{1s}$ ,  $\text{Si}_{2p_{3/2}}$ , and  $\text{O}_{1s}$ , respectively. The spectra of  $\text{C}_{1s}$ , shown in Fig. 12(a), suggest an increase of  $\text{Li}_2\text{CO}_3$ , ( $\text{C}=\text{O}$  peak at ca. 289 eV (ref. 45)) with charge–discharge cycle. The formation of  $\text{Li}_2\text{CO}_3$  was also suggested by the EELS spectra shown in Fig. 9 and 10. The peaks at 284–286 eV, which were observed in all spectra, are attributed to the overlapping of several C–C and C–O bonds.

The spectra of  $\text{Li}_{1s}$  shown in Fig. 12(b), suggest the appearance of  $\text{Li}_2\text{CO}_3$ ,  $\text{Li}_2\text{O}$ , and Li alloyed with silicon after the 1st charge. By comparing the spectra of charged and discharged samples at the same cycle number, the peak attributed to Li could be seen to increase after charging. Although the absolute intensities were incommensurable, the decrease in Li/ $\text{Li}_2\text{O}$  in each cycle was confirmed. These results imply that the lithiation and delithiation of silicon occurred during charge and discharge, respectively. The peak shift, which was attributed to the increase in the  $\text{Li}_2\text{CO}_3$  content of the Li–Si–O–C composite anodes, was confirmed to occur with increasing number of cycles, as also suggested by EELS analysis. In addition, the phases of  $\text{Li}_2\text{CO}_3$  and  $\text{Li}_2\text{O}$  were suggested to have remained unchanged during the charge–discharge cycles. The unchanged phases should act as a buffer against volume change during charge–discharge cycles, resulting in such a highly durable silicon based anode suitable for lithium secondary batteries.

The  $\text{Si}_{2p_{3/2}}$  spectra shown in Fig. 12(c) suggest that the silicon in the Si–O–C composite film existed in the form of Si,  $\text{SiO}_2$  and intermediate oxides of silicon. The results correspond to those of the EELS analysis. Taking into consideration that the discharge capacity was delivered and that the existence of

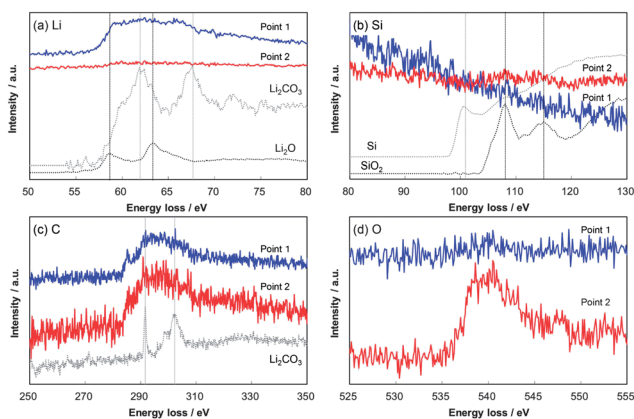
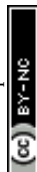


Fig. 10 EELS spectra of Li (a), Si (b), C (c), and O (d) obtained at different locations on the Li–Si–O–C composite anode after the 1st charge. The spectra of  $\text{SiO}_2$ , Si,  $\text{Li}_2\text{O}$ , and  $\text{Li}_2\text{CO}_3$  standard samples are also included. The baselines of each graph have been displaced for clarity. Reproduced from data published in ref. 37.



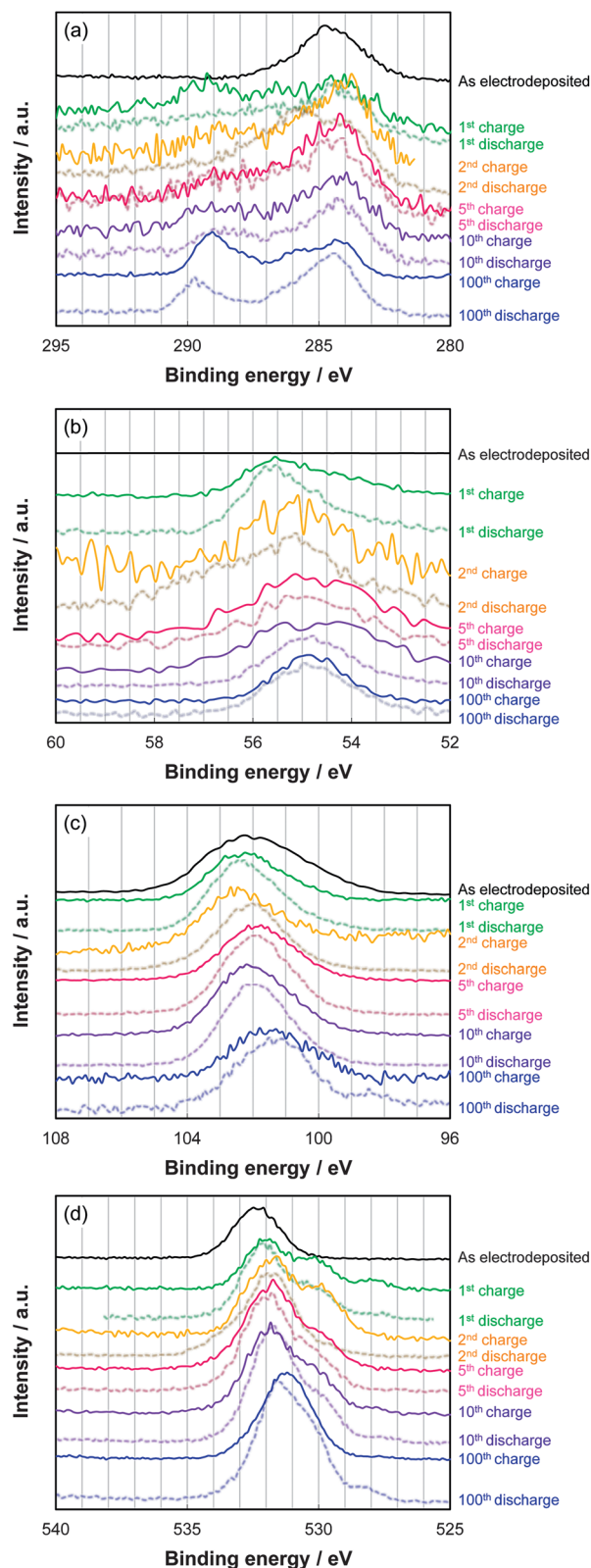


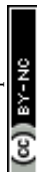
Fig. 12 XPS spectra of  $C_{1s}$  (a),  $Li_{1s}$  (b),  $Si_{2p3/2}$  (c), and  $O_{1s}$  (d) on the Si–O–C composite film and Li–Si–O–C composite anodes after the 1st charge, 1st discharge, 2nd charge, 2nd discharge, 5th charge, 5th discharge, 10th charge, 10th discharge, 100th charge, and 100th discharge. All spectra were corrected based on the C–C bond at 284 eV after peak separation of the  $C_{1s}$  spectra into C–C, C–O, and C=O peaks. The baselines of each graph are displaced for clarity. Reproduced from data published in ref. 37.

lithium was confirmed by the EELS analysis, the silicon in the Si–O–C composite film should react with lithium ions during the 1st charge process. However, although the shift of peak position to a lower binding energy due to silicon lithiation was confirmed, the peaks remained located mostly at *ca.* 102 eV. This result suggests that lithium silicates such as  $Li_xSiO_4$  were formed instead of  $Li_xSi$ , as has been reported by several groups.<sup>13,46</sup> Comparing the charged state with the discharged state in each cycle shows that the intensity of the peaks at a lower binding energy increased after discharge. This difference is attributable to the formation of  $Li_xSi$  due to the lithiation of  $SiO_x$ . Therefore, it is suggested that  $Li_xSi$  and lithium silicates are formed in the charged state of Li–Si–O–C composite anodes.

The broad peak in the  $O_{1s}$  spectra shown in Fig. 12(d) is likely to be composed of several peaks attributed to  $SiO_2$  as the main phase and to Si–O and C–O bonding. Peaks attributed to  $Li_2O$  and  $Li_2CO_3$  were also observed. The broad peak shifted toward lower binding energies after the 1st charge, which was apparently caused by the reduction of  $SiO_2$  by lithiation. The peak at *ca.* 532 eV was attributed to  $Li_4SiO_4$  as reported in a previously published paper.<sup>46</sup> Additional peaks appeared at 530–531 eV after the 1st charge. These peaks were observable even after the 1st discharge and subsequent cycles. Because the magnitude of the peaks decreased after each discharge, the peaks appear to be related to lithiation. This phenomenon corresponds to the reversible conversion reaction of  $SiO_2$  into  $Li_2Si_2O_5$ , as reported by Sun *et al.*<sup>47</sup> The peaks of  $Li_2Si_2O_5$  are reported to be at 530.7 and 532.5 eV.<sup>13,48</sup> While these peaks would be expected to decrease after discharge, the observed peak remained at 530–531 eV. This result therefore implies the existence of irreversible lithium silicates. The peaks of  $Li_2SiO_3$  and  $Li_2Si_2O_3$  are also reported to appear at 530.3 eV (ref. 46) and 530.8, 532.4 eV,<sup>13,48</sup> respectively. Therefore, the Li–Si–O–C composite anode is suggested to contain several different lithium silicate states. Because the peak at 532 eV was observed independently of the charge state and the cycle number,  $Li_4SiO_4$  consistently appears to exist in the Li–Si–O–C composite anode. The peaks shifted to lower binding energies with increasing cycle number, which implies the possibility of a transformation of  $Li_4SiO_4$  to  $Li_2SiO_3$ .

### Mechanism of Si–O–C composite film formation

From the EDX, EELS, and XPS analyses, the Si–O–C composite film was suggested to be uniformly composed of  $SiO_x$  and organic compounds. Such a uniform Si–O–C composite film can be achieved by the simultaneous deposition of silicon and organic compounds as mentioned above. This was also supported by linear sweep voltammogram (LSV) of the electrodeposition bath composed of propylene carbonate (PC) and  $TBAClO_4$  with  $SiCl_4$  and glow discharge-optical emission spectroscopy (GDOES). The linear sweep voltammogram in Fig. 13 indicates that the deposition of  $SiCl_4$  begins at *ca.* 1.3 V vs.  $Li/Li^+$ . In contrast, the decomposition of PC or  $TBAClO_4$  begins at *ca.* 0.45 V vs.  $Li/Li^+$ . PC and  $TBAClO_4$  may be considered to be stable against reduction above a potential of *ca.* 0.45 V vs.  $Li/Li^+$ . However, the decomposition of the electrolyte must have occurred due the fact that a small cathodic current was



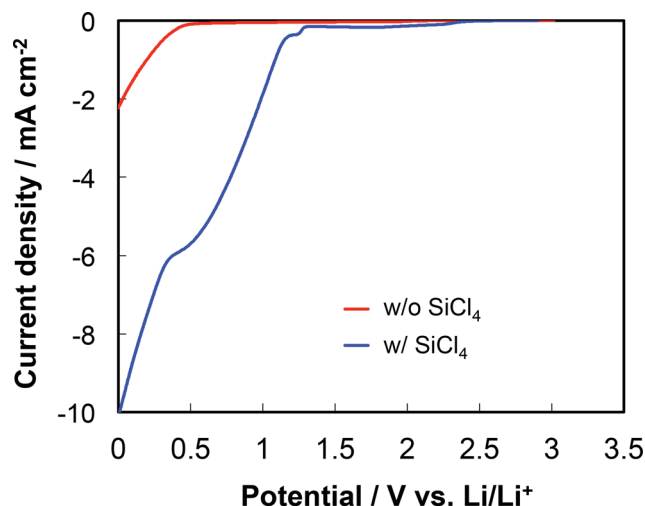


Fig. 13 Linear sweep voltammogram of electrodeposition bath containing PC and TBAClO<sub>4</sub> with or without SiCl<sub>4</sub>. Scan rate is 1.0 mV s<sup>-1</sup> in the cathodic direction. Reproduced from the data published in ref. 36.

confirmed over the entire range and that the amount of silicon in the Si–O–C composite film, which was electrodeposited at a constant current of 0.7 mA cm<sup>-2</sup> and a potential of ca. 1.3 V vs. Li/Li<sup>+</sup>, was 60 wt% from the GDOES data (not shown). So far, it is difficult to conclude that the SiCl<sub>4</sub> accelerated the decomposition of the electrolyte or that impurities in the SiCl<sub>4</sub> decomposed. However, the facts suggest that the coinstantaneous deposition of silicon and organic compounds is possible at a potential of ca. 1.3 V vs. Li/Li<sup>+</sup> in the present case.

Fig. 14 schematically illustrates the electrodeposition of the Si–O–C composite film summarized from the analytical data. SiCl<sub>4</sub> and PC are decomposed simultaneously by electrons that are conducted through the deposit, resulting in the formation of the Si–O–C composite film. The composite film is composed of SiO<sub>x</sub>, which is a mixture of Si and SiO<sub>2</sub> as shown by EELS analysis, and organic compounds. After the 1st lithiation, SiO<sub>x</sub> is converted to Li<sub>x</sub>Si, Li<sub>2</sub>O, and lithium silicates and SEI, as typified by Li<sub>2</sub>CO<sub>3</sub>, are formed by the decomposition of the

electrolyte. The mixture of active materials such as Si and Li<sub>2</sub>Si<sub>2</sub>O<sub>5</sub> and inactive materials such as Li<sub>2</sub>O, Li<sub>2</sub>CO<sub>3</sub>, and organic compounds results in outstanding properties for a lithium secondary battery anode.

## Summary

The increase of energy density on energy storage is essential to make our sustainable life with a future come true. The reasons to increase the energy density of batteries are to increase the capacity of both anode and cathode, to expand the potential difference between anode and cathode, and to balance the capacities between anode and cathode: of course, decrease of weight and volume of other components in batteries is also important. For the purpose, the active materials of anode and cathode have been shifting to alloying materials (including conversion materials) from insertion materials. However, the alloying materials have some problems which should be solved for their practical application, namely, volume change during charge–discharge cycles, and low electric conductivity and low ionic conductivity in the materials. Especially, the volume change during charge–discharge cycles is a crucial problem for anode materials such as Si and Sn, resulting in capacity decay caused by pulverization of the active material. To solve those problems, materials design such as reduction in size down to nanometric scale and two-dimensionalization of the materials, and combination with carbon materials have been proposed. Firstly, this paper reviewed recent work on silicon-based anodes to overcome the poor cycle durability from the standpoints of structural control such as with thin films,<sup>4–6</sup> porous structures,<sup>7,8,49</sup> core–shell structures,<sup>14–16,50</sup> nano structures,<sup>23,24,51</sup> and by alloying with other metals.<sup>25–27,29</sup> All these efforts have been focused on the reduction of the stress experienced during charge–discharge cycling by nano-structuring the material and/or surrounding materials to buffer the stress. The approaches used can be divided into two types. The first is nano-structured powder, which is suitable for conventional processes used to assemble batteries and can increase the capacity of the electrode by increasing its thickness. Cui's group has kept the heat on the development of nano-structured silicon materials.<sup>14,49–52</sup> Among them, the work on the DWSiNT anode demonstrated high durability for charge–discharge cycles *i.e.* 88% capacity retention even after 6000 cycles.<sup>14</sup> Coinstantaneously, good binders that suppress the degradation of silicon-based anodes have also been developed.<sup>32,34,53</sup> The other is a nano-structured film deposited directly onto the substrate that does not require any other additives such as electron conductor and binder. The applications of these two types will therefore be different; nano-structured powder will be preferentially applied in high-energy-oriented batteries because it can be made thick, and the nano-structured film will be preferentially applied in energy density-oriented batteries because other additives are not required. The Si–O–C composite film has the potential to achieve both properties, leading to much higher energy density, because the thickness of the Si–O–C composite film can be increased without any additives by increasing the columbic amount for electrodeposition.<sup>38</sup> Moreover, the technique of

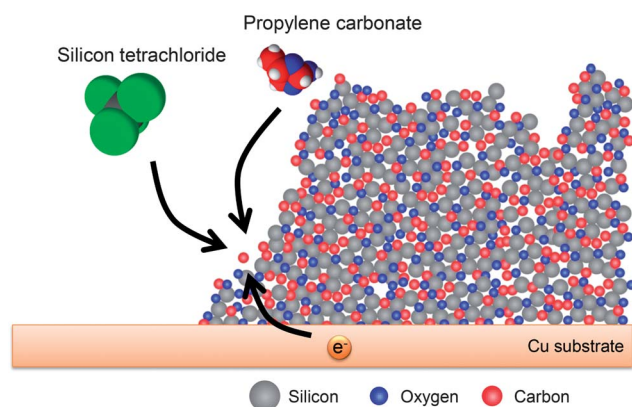


Fig. 14 Schematic of the electrodeposition of the Si–O–C composite film. Reproduced from data published in ref. 36.





alloy anode preparation by electrodeposition is applicable to other materials that can alloy with lithium.<sup>54</sup> This paper focused especially on a binder-free Si–O–C composite film for lithium secondary battery anodes that delivered a discharge capacity of 1125 mA h (g of Si)<sup>−1</sup> or 693 mA h (g of deposit)<sup>−1</sup> at the 500th cycle and can operate even over 7000 charge–discharge cycles with a discharge capacity of 831 mA h (g of Si)<sup>−1</sup> or 512 mA h (g of deposit)<sup>−1</sup>. The mechanism of the Si–O–C composite film formation was discussed using STEM, EELS, and XPS data. The results suggested that the mixture of active materials such as Si and Li<sub>2</sub>Si<sub>2</sub>O<sub>5</sub> and inactive materials such as Li<sub>2</sub>O, Li<sub>2</sub>CO<sub>3</sub>, and organic compounds results in outstanding properties for a lithium secondary battery anode.

Silicon anode-based lithium ion batteries will become standard batteries like the lead-acid battery, which has been used for over 150 years in various applications, in future because of its high theoretical capacity. Therefore, a cathode should be also developed for the realization of silicon anode-based lithium ion batteries. The replacement of the graphite anode with a silicon-based anode in a conventional LIB system can hardly ask for drastic increase in capacity in the same manner mentioned in Fig. 2. Fortunately, numerous efforts to increase the capacity of cathode have been made. For example, sulfur cathodes, which exhibit high capacity, have been investigated.<sup>55</sup> In addition, some studies that combine conversion anodes with sulfur cathodes have been reported.<sup>56</sup> Thus, the lithium ion battery composed of the silicon-based anode and sulfur-based cathode will be realized in the near future. A battery with air cathode has been also investigated as an ultimate battery with high energy density.<sup>57</sup> Even in the battery system for the future, silicon-based anode can be one of the choices for safety issue due to the reactivity of lithium metal.<sup>58</sup> Therefore, the silicon-based anode will be one of the critical technologies for future energy storage.

## Acknowledgements

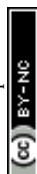
We acknowledge the support by the Grant-in-Aid for Specially Promoted Research “Establishment of Electrochemical Device Engineering” from the Ministry of Education, Culture, Sports, Science and Technology, Japan. We also acknowledge the support in part by the “Research & Development Initiative for Scientific Innovation of New Generation Batteries” of the New Energy and Industrial Technology Development Organization of Japan.

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